

#### **Maximum Ratings**

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature65°C to +150°C
Supply Voltage to Ground Potential0.5V to +2.5V
DC Input Voltage $-0.5$ V to $+$ V <sub>DD</sub>
DC Output Current
Power Dissipation

**Note:** Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## **Power Supply Characteristics**

Parameters	Description	Test Conditions <sup>(1)</sup>	Min.	Typ. <sup>(2)</sup>	Max.	Units
$I_{\mathrm{DD}}$	Quiescent Power Supply Current	$V_{DD} = Max., V_{IN} = GND \text{ or } V_{DD}$			400	μΑ

#### Notes:

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at  $V_{DD} = 1.8V$ ,  $T_A = 25$ °C ambient and maximum loading.

## DC Electrical Characteristics for Switching over Operating Range

 $(T_A = -40^{\circ}C \text{ to } +85^{\circ}C, V_{DD} = 1.5V \text{ to } 1.8V \pm 10\%)$ 

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units	
$V_{\mathrm{IH}}$	Input HIGH Voltage, SEL input	Guaranteed HIGH level	0.65 x V <sub>DD</sub>	-	-		
$V_{ m IL}$	Input LOW Voltage, SEL input	Guaranteed LOW level	-0.5	-	0.35 x V <sub>DD</sub>	V	
V <sub>IK</sub>	Clamp Diode Voltage, SEL input	$V_{DD} = Max., I_{IN} = -18mA$	-	-0.7	-1.2		
$I_{\mathrm{IH}}$	Input HIGH Current for SEL	$V_{DD} = Max., V_{IN} = V_{DD}$	-10	-	+10		
$I_{OZ}$	Channel Leakage Current	$V_{DD} = Max., V_{IN} = 1.8V$	-10	ı	+10	μΑ	
$I_{\mathrm{IL}}$	Input LOW Current	$V_{DD} = Max., V_{IN} = GND$	-20	-	+10		
Vma	DC Signal Voltage Range	$V_O/V_I > 95\%$ , $R_L = 10K$	-0.5		2.5	V	
$V_{\mathrm{IDC}}$	De Signal voltage Range	$V_O/V_I > 80\%$ , $R_L = 50$ -Ohms	-0.4		1.2	'	

#### **Switching Characteristics**

 $(T_A = -40^{\circ} \text{ to } +85^{\circ}\text{C}, V_{DD} = 1.5\text{V to } 1.8\text{V} \pm 10\%)$ 

Parameter	Description	Min.	Тур.	Max.	Units	
tpzh, tpzl	Line Enable Time - SEL to A <sub>N</sub> , B <sub>N</sub> , C <sub>N</sub>	0.5	-	9.0	***	
tpHZ, tPLZ	Line Disable Time - SEL to A <sub>N</sub> , B <sub>N</sub> , C <sub>N</sub>	0.5	-	9.0	ns	
t <sub>b-b</sub>	Bit-to-bit skew within the same differential pair			10		
tch-ch	Channel-to-channel skew 15		15	ps		
tdiff	Differential delay - A <sub>N</sub> to B <sub>N</sub> or C <sub>N</sub>			20		

#### Notes:

<sup>1.</sup> For max. or min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.



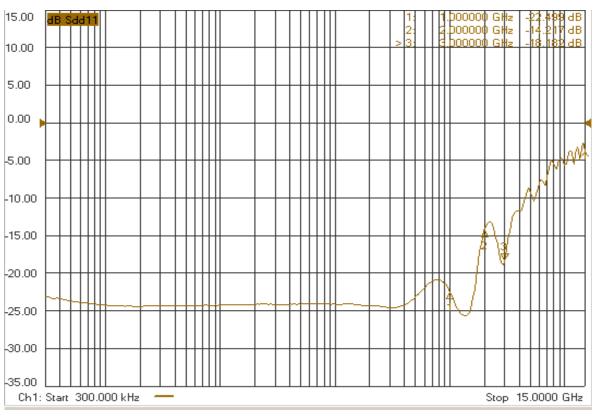
# Dynamic Electrical Characteristics Over the Operating Range (TA= -40° to +85°C, $V_{DD}$ = 1.5V to 1.8V $\pm 10\%$ )

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units
BW	Bandwidth -3dB			4.1		
		Insertion loss 1.5dB, V <sub>IN</sub> =0.8Vpp, DC=0V	2.5			
V <sub>z</sub> -	Max Signal Frequency	Insertion loss 1.5dB, V <sub>IN</sub> =0.6Vpp, DC=0.9V	2.5			GHz
V <sub>IF</sub>	Range	Insertion loss 3dB, V <sub>IN</sub> =0.8Vpp, DC=0V	4.0			
		Insertion loss 3dB, V <sub>IN</sub> =0.6Vpp, DC=0.9V	4.0			
		$R_L = 50$ , f=375MHz, sin wave, DC=0V	1.2			
P-1dB	1 dB Compression Input Signal	R <sub>L</sub> = 50, f=375MHz, sin wave, DC=0.45V	2.0			Vpp
		R <sub>L</sub> = 50, f=375MHz, sin wave, DC=0.9V	2.4			
R <sub>LOSS</sub>	Return Loss	f=3 GHz		-18		
X <sub>TALK</sub>	Crosstalk	f = 3.0 GHz		-43		
O <sub>IRR</sub>	OFF Isolation	f = 3.0 GHz		-21		dB
I <sub>LOSS</sub>	Differential Insertion Loss	f= 3 GHz		-2.3		

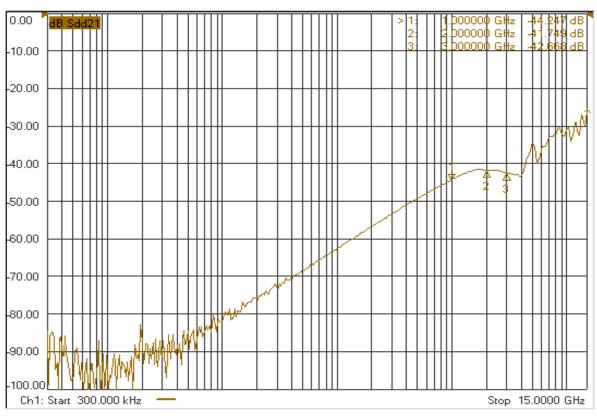
#### **Notes:**

Guaranteed by design.



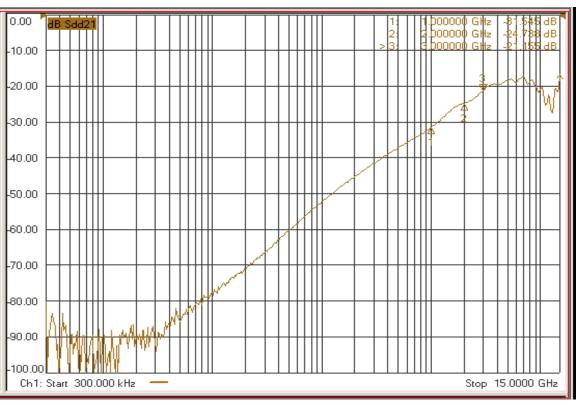


#### **Return Loss**

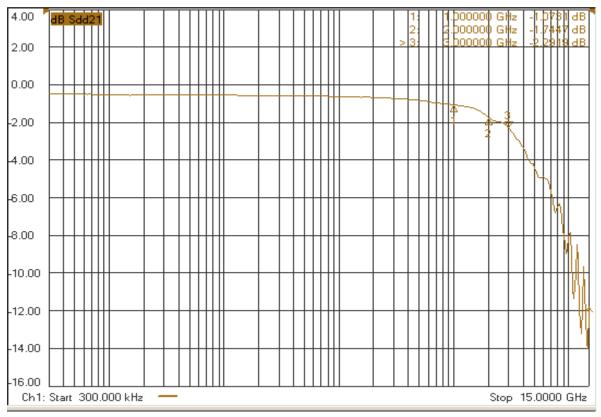


Crosstalk



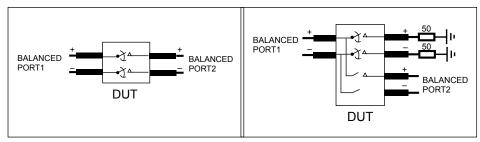


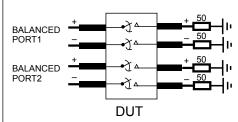
### **Off Isolation**



**Insertion Loss** 





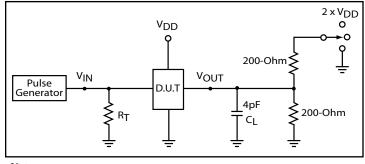


Diff. Insertion Loss and Return Test Circuit

**Diff. Off Isolation Test Circuit** 

Diff. Near End Xtalk Test Circuit

## <u>Test Circuit for Electrical Characteristics</u><sup>(1-5)</sup>



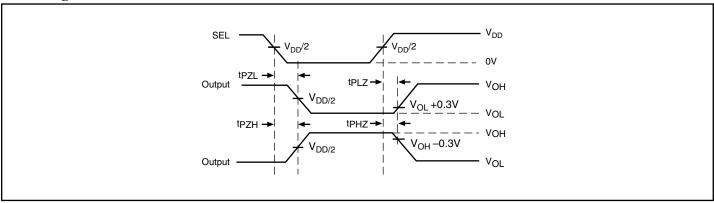
## **Switch Positions**

Test	Switch
t <sub>PLZ</sub> , t <sub>PZL</sub>	2 x V <sub>DD</sub>
t <sub>PHZ</sub> , t <sub>PZH</sub>	GND
Prop Delay	Open

#### Notes:

- 1. C<sub>L</sub> = Load capacitance: includes jig and probe capacitance.
- 2.  $R_T$  = Termination resistance: should be equal to  $Z_{OUT}$  of the Pulse Generator
- Output 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
   output 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- 4. All input impulses are supplied by generators having the following characteristics:  $PRR \le MHz$ ,  $Z_Q = 50\Omega$ ,  $t_R \le 2.5$ ns,  $t_F \le 2.5$ ns.
- 5. The outputs are measured one at a time with one transition per measurement.

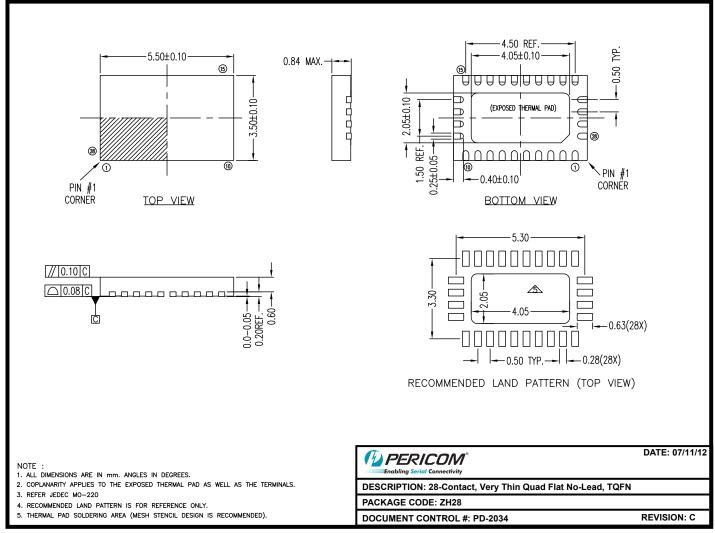
## **Switching Waveforms**



**Voltage Waveforms Enable and Disable Times** 



## Packaging Mechanical: 28-Pin TQFN (ZH)



12-0419

#### Note:

• For latest package info, please check: http://www.pericom.com/products/packaging/mechanicals.php

### **Ordering Information**

Ordering Code	Package Code	Package Type
PI2DBS6212ZHEX	ZH	28-contact, Very Thin Quad Flat No-Lead (TQFN)

#### **Notes:**

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- E = Pb-free and Green
- Adding an X suffix = Tape/Reel

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